

20V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D @ T _A = 25°C
	495mΩ @ V _{GS} = -4.5V	-0.77A
-20V	690mΩ @ V _{GS} = -2.5V	-0.67A
	960mΩ @ V _{GS} = -1.8V	-0.57A

Features and Benefits

- Footprint of just 0.6mm² thirteen times smaller than SOT23
- 0.4mm profile ideal for low profile applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- ESD Protected Gate 3KV
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Portable electronics

Mechanical Data

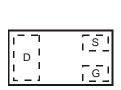
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)



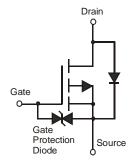




Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 3)

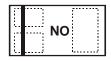
Ī	Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	DMP21D0UFB4-7B	NO	7	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information

DMP21D0UFB4-7B



Top View Bar Denotes Gate and Source Side

NO = Product Type Marking Code



Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current	Steady State	$T_A = 25$ °C (Note 4) $T_A = 85$ °C (Note 4) $T_A = 25$ °C (Note 5)	I _D	-0.77 -0.55 -1.17	А
Pulsed Drain Current (Note 6)			I _{DM}	-5.0	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	0.43	W
Power Dissipation (Note 5)	P _D	0.99	W
Thermal Resistance, Junction to Ambient (Note 4)	R _{0JA}	293	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	126	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Thermal Characteristics

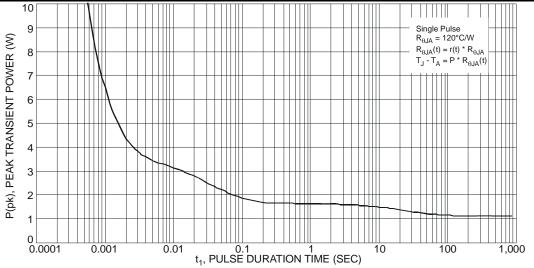
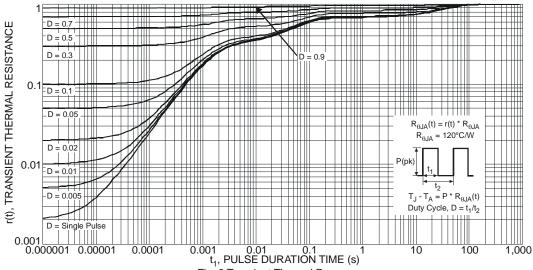


Fig. 1 Single Pulse Maximum Power Dissipation





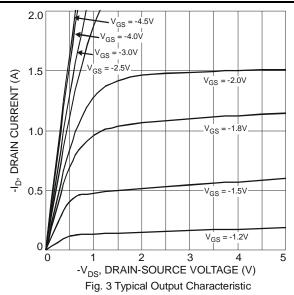
Electrical Characteristics @T_A = 25°C unless otherwise specified

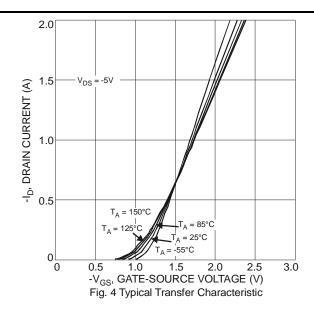
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	-1	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±10	μΑ	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	a .					_	
Gate Threshold Voltage	$V_{GS(th)}$	1	-0.7	-	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
				495		$V_{GS} = -4.5V, I_D = -400mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}	-	-	690	mΩ	$V_{GS} = -2.5V, I_D = -300mA$	
				960		$V_{GS} = -1.8V, I_D = -100mA$	
Forward Transfer Admittance	Y _{fs}	50	-	-	mS	$V_{DS} = -3V, I_{D} = -300 \text{mA}$	
Diode Forward Voltage	V_{SD}	1	-	-1.2	V	$V_{GS} = 0V, I_{S} = -300 \text{mA}$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	-	76.5	-	pF	101/11/101/	
Output Capacitance	Coss	-	13.7	-	pF	$V_{DS} = -10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	10.7	-	pF		
Gate Resistance	Rg	-	195	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Q_g		1.5	-	nC	$V_{GS} = -8V$, $V_{DS} = -15V$, $I_{D} = -1A$	
Total Gate Charge	Q_g	-	1.0	-	nC	V _{GS} = -4.5V, V _{DS} = -15V, I _D = -1A	
Gate-Source Charge	Q _{gs}	-	0.2	-	nC		
Gate-Drain Charge	Q_{gd}	-	0.3	-	nC		
Turn-On Delay Time	t _{D(on)}	-	7.1	-	ns	V _{DS} = -10V, -I _D = 1A	
Turn-On Rise Time	t _r	-	8.0	-	ns		
Turn-Off Delay Time	t _{D(off)}	-	31.7	-	ns	V_{GS} = -4.5V, R_{G} = 6Ω	
Turn-Off Fall Time	t _f	-	18.5	-	ns		

Notes:

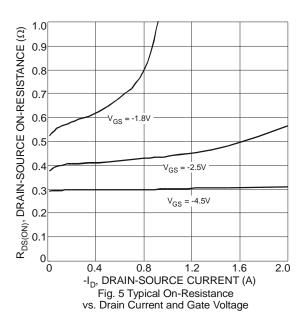
- 4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout
- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate
 Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.
 Short duration pulse test used to minimize self-heating effect.

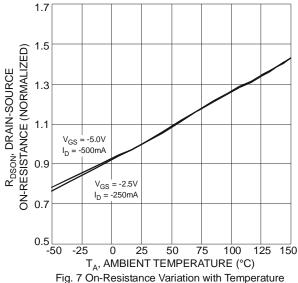
Typical Characteristics

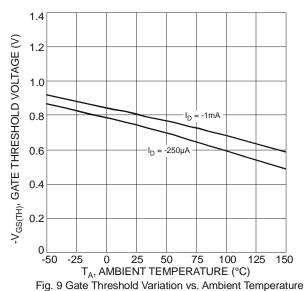


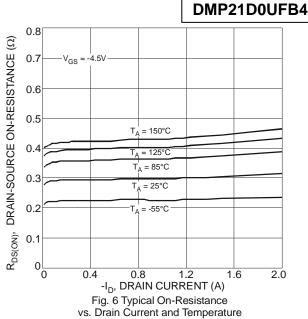


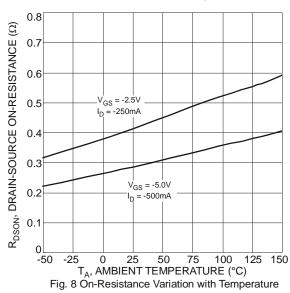


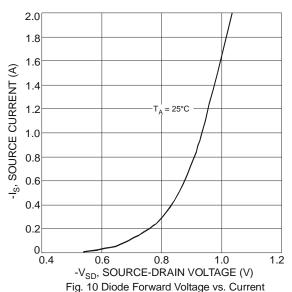




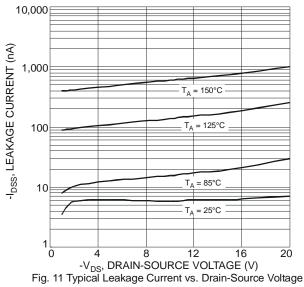


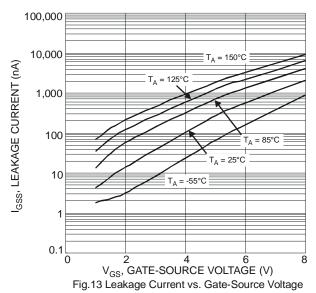


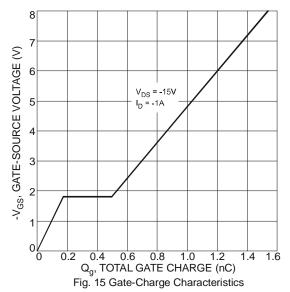


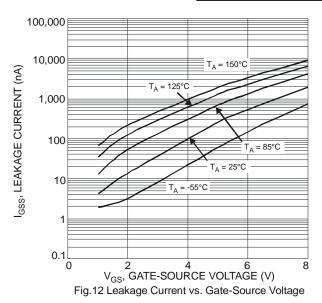


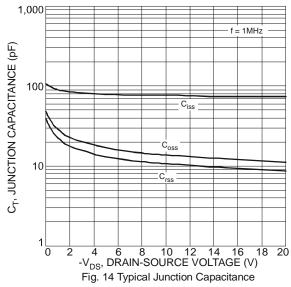






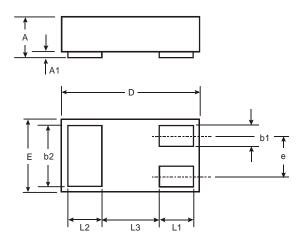






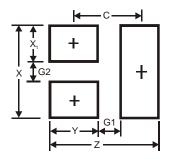


Package Outline Dimensions



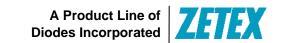
	X2-DFN1006-3					
Dim	Min	Max	Тур			
Α		0.40				
A1	0	0.05	0.03			
b1	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95 1.05		1.00			
Е	0.55	0.65	0.60			
е			0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3			0.40			
All	All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Υ	0.4
С	0.7





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